

General Description

The AOZ8035 is a 6-line device integrating EMI filtering with ESD protection for each line. It is designed to suppress unwanted EMI/RFI signals and provide electrostatic discharge (ESD) protection in portable electronic equipment. This state-of-the-art device utilizes AOS leading edge Trench Vertical Structure [TVS]²™ technology for superior clamping performance and filter attenuation over the full operating display range. The AOZ8035 has been optimized for protection of color LCD displays and CCD camera lines in cellular phones and other portable consumer electronic devices.

The AOZ8035 consists of six identical circuits comprised of TVS diodes for ESD protection, and a resistor-capacitor network for EMI/RFI filtering. A series resistor value of 100 Ω and a capacitance value of 28 pF are used to achieve -35 dB minimum attenuation from 800 MHz to 3.0 GHz. The TVS diodes provide effective suppression of ESD voltages in excess of ± 20 kV (contact discharge) and ± 20 kV (air discharge). This exceeds the IEC 61000-4-2, level 4 ESD immunity test.

The AOZ8035 comes in an RoHS compliant, 2.50 mm x 1.20 mm DFN package and is rated over a -40 °C to +85 °C ambient temperature range.

Features

- 6 lines for EMI filtering and ESD protection:
 - Exceeds IEC 61000-4-2, level 4 (ESD) immunity test
 - ± 20 kV (contact discharge) and ± 20 kV (air discharge)
- Trench Vertical Structure [TVS]²™ based technology used to achieve excellent ESD clamping & filter performance over the full operating display range
- Filter performance: -35 dB attenuation from 800 MHz to 3.0 GHz
- Low operating voltage: 5.0 V
- Capacitance stability over wide range of voltages and temperatures
- DFN package 2.50 mm x 1.20 mm
- Pb-free device

Applications

- EMI filtering and ESD protection for data lines
- LCD displays, camera interface, I/O interface
- Portable handheld devices, cell phones, PDA phones



Electrical Schematic

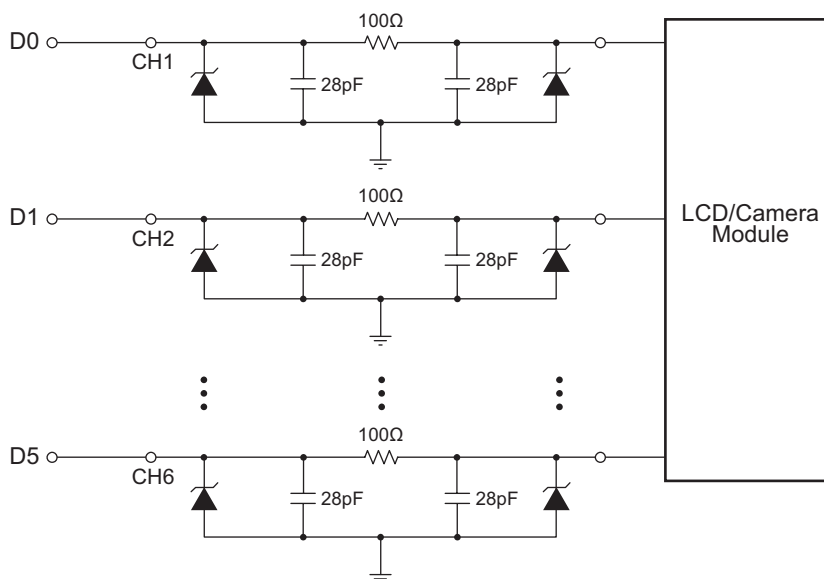


Figure 1

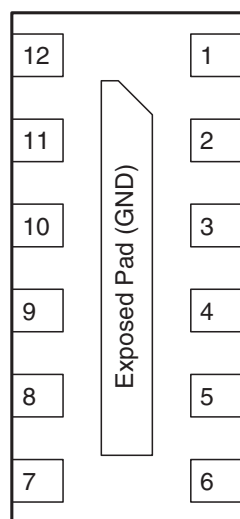
Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental
AOZ8035DIL	-40 °C to +85 °C	DFN-12	RoHS Compliant Green Product

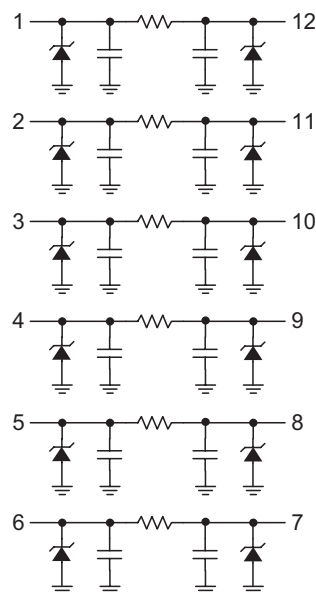


All AOS products are offered in packages with Pb-free plating and compliant to RoHS standards.
Parts marked as Green Products (with "L" suffix) use reduced levels of Halogens, and are also RoHS compliant.
Please visit www.aosmd.com/web/quality/rohs_compliant.jsp for additional information.

Pin Configuration



DFN-12
(Bottom View)



Top View

Pin Description

Pin Number	Pin Name	Pin Function
1,12	CH 1	Channel 1 Connections
2, 11	CH 2	Channel 2 Connections
3, 10	CH 3	Channel 3 Connections
4, 9	CH 4	Channel 4 Connections
5, 8	CH 5	Channel 5 Connections
6, 7	CH 6	Channel 6 Connections
Exposed Pad	GND	Common Ground Connection

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating
Storage Temperature (T_S)	-65 °C to +150 °C
ESD Rating per IEC61000-4-2, contact ⁽¹⁾	±20 kV
ESD Rating per IEC61000-4-2, air ⁽¹⁾	±20 kV
ESD Rating per Human Body Model ⁽²⁾	±30 kV

Notes:

1. IEC 61000-4-2 discharge with $C_{Discharge} = 150\text{pF}$, $R_{Discharge} = 330\Omega$.
2. Human Body Discharge per MIL-STD-883, Method 3015 $C_{Discharge} = 100\text{pF}$, $R_{Discharge} = 1.5\text{k}\Omega$.

Electrical Characteristics

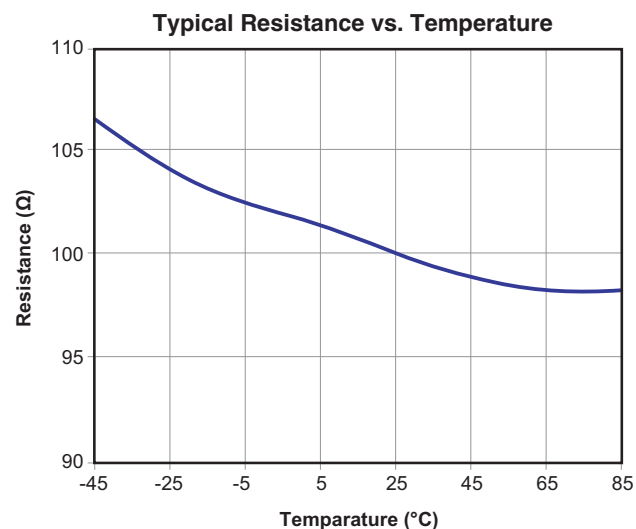
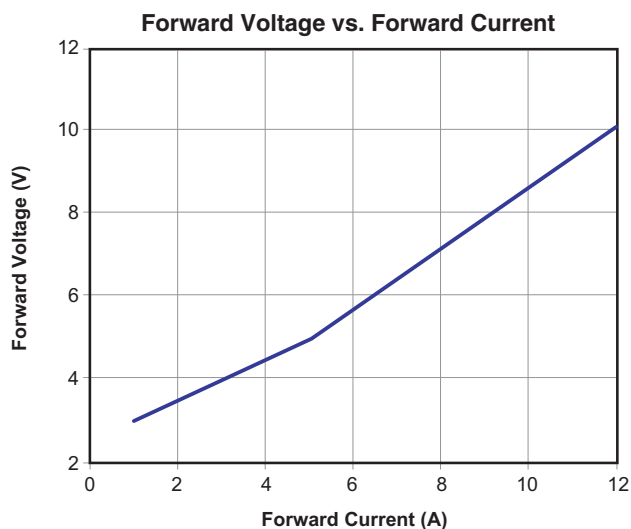
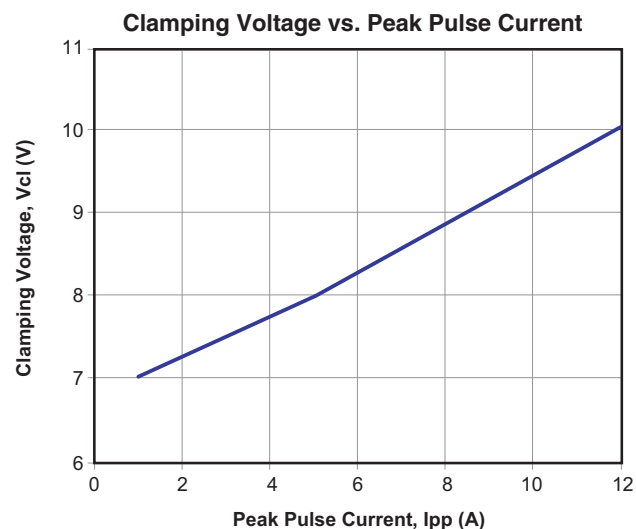
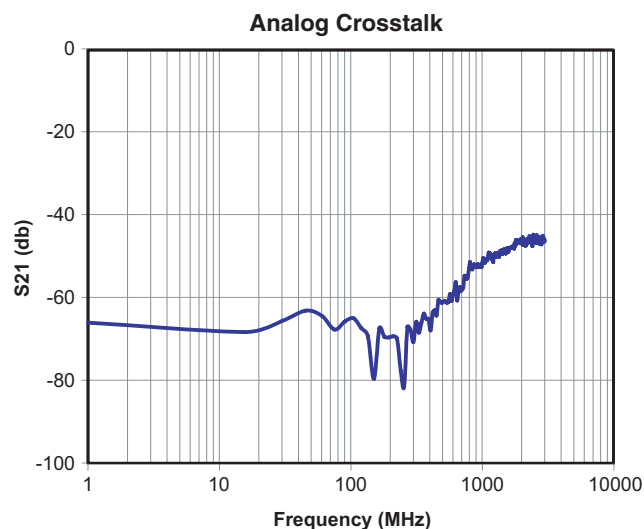
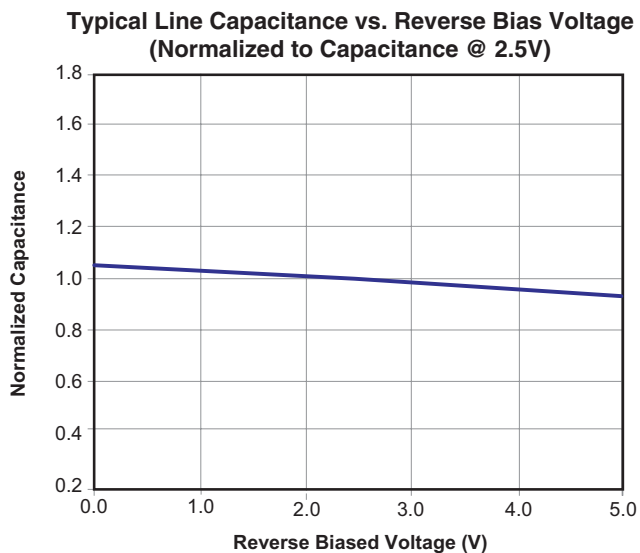
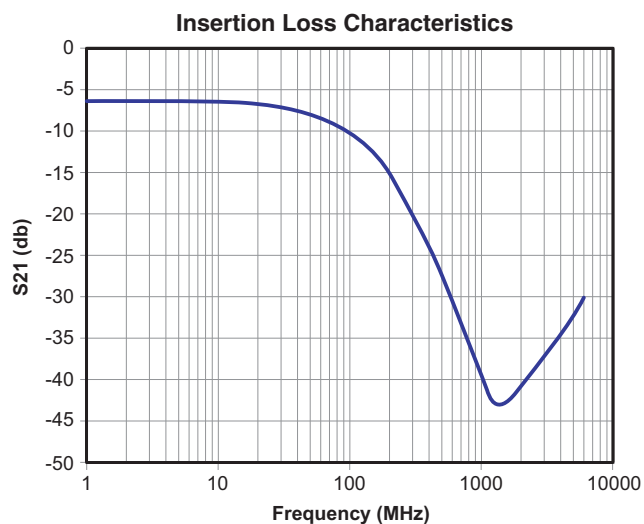
$T_A = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{RWM}	Reverse Working Voltage	(3)(8)			5.0	V
V_{BR}	Reverse Breakdown Voltage	$I_T = 1\text{ mA}$ ⁽⁴⁾	6	7	8	V
I_R	Reverse Leakage Current	$V_{RWM} = 3.3\text{ V}$			0.1	μA
V_{CL}	Signal Clamp Voltage	$I_{LOAD} = 1\text{ A}$, positive clamp ⁽⁵⁾⁽⁸⁾			7.00	V
		$I_{LOAD} = 1\text{ A}$, negative clamp ⁽⁵⁾⁽⁸⁾			-3.00	
		$I_{LOAD} = 5\text{ A}$, positive clamp ⁽⁵⁾⁽⁸⁾			8.00	
		$I_{LOAD} = 5\text{ A}$, negative clamp ⁽⁵⁾⁽⁸⁾			-5.00	
		$I_{LOAD} = 12\text{ A}$, positive clamp ⁽⁵⁾⁽⁸⁾			10.00	
		$I_{LOAD} = 12\text{ A}$, negative clamp ⁽⁵⁾⁽⁸⁾			-10.00	
R_{CH}	Total Series Resistance	$I_R = 20\text{ mA}$	90	100	110	Ω
C_{CH}	Channel Capacitance	Input to Ground ⁽⁶⁾⁽⁷⁾⁽⁸⁾	26	28	30	pF
f_C	Cut-off Frequency	Measured with 50Ω source and 50Ω load termination		90		MHz
	Attenuation from 800MHz to 3.0GHz	Measured with 50Ω source and 50Ω load termination		-35		dB

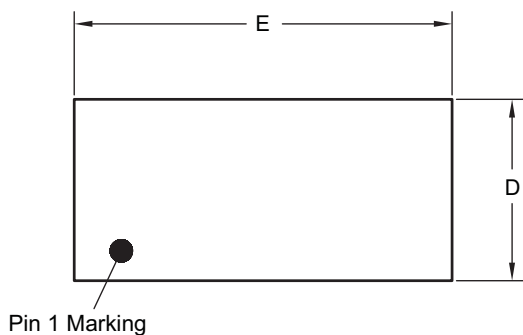
Notes:

3. The working peak reverse voltage, V_{RWM} , should be equal to or greater than the DC or continuous peak operating voltage level.
4. V_{BR} is measured at the pulse test current I_T .
5. Measurements performed using a 100 ns Transmission Line Pulse (TLP) system.
6. Total capacitance is equal to $2 \times C_{CH}$.
7. Measured at 25°C , $V_R = 2.5\text{ V}$, $f = 1.0\text{ MHz}$.
8. Guaranteed by design.

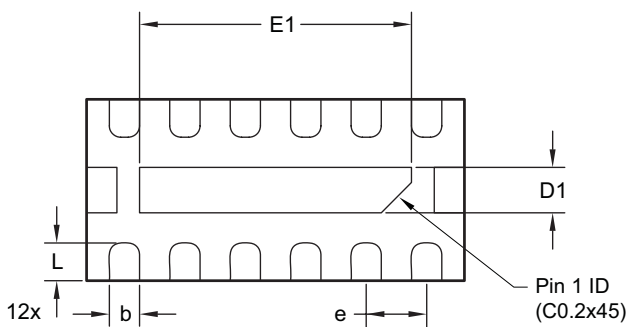
Typical Performance Characteristics



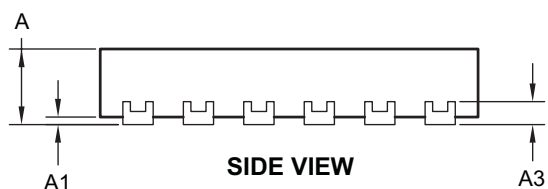
Package Dimensions, DFN 2.5 mm x 1.2 mm, 12L EP1 S



TOP VIEW

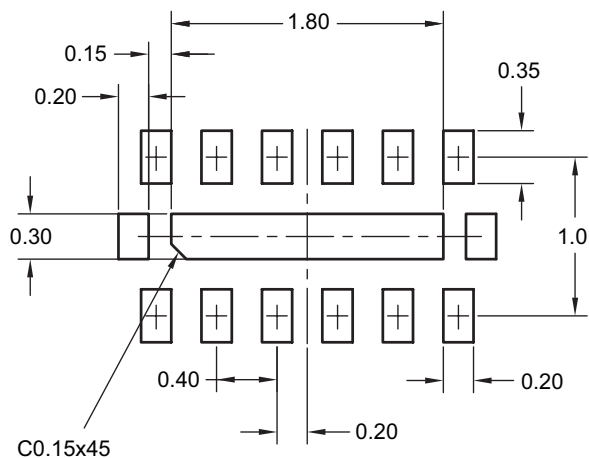


BOTTOM VIEW



SIDE VIEW

RECOMMENDED LAND PATTERN



UNIT: mm

Dimensions in millimeters

Symbols	Min.	Nom.	Max.
A	0.50	0.55	0.60
A1	0.00	—	0.05
b	0.15	0.20	0.25
A3	0.152 REF		
D	1.15	1.20	1.25
E	2.45	2.50	2.55
D1	0.25	0.30	0.35
D1	1.75	1.80	1.85
e	0.40 BSC		
L	0.20	0.24	0.30

Dimensions in inches

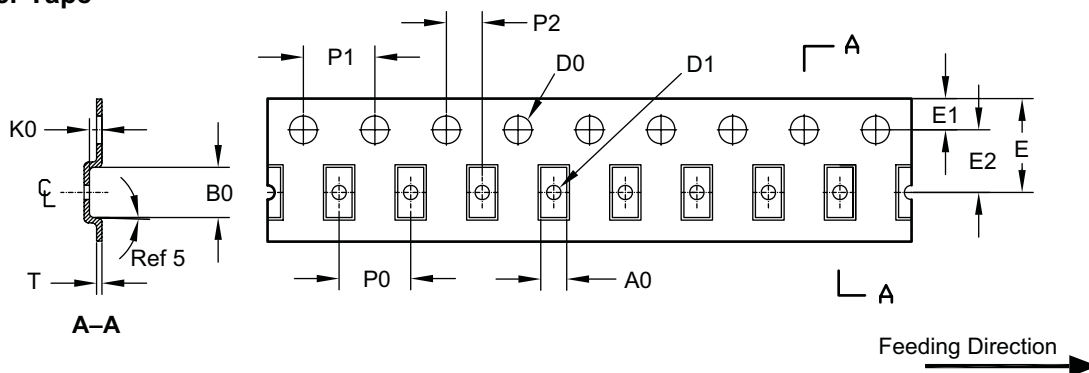
Symbols	Min.	Nom.	Max.
A	0.020	0.022	0.024
A1	0.000	—	0.002
b	0.006	0.008	0.010
A3	0.006 REF		
D	0.045	0.047	0.049
E	0.096	0.098	0.100
D1	0.010	0.012	0.014
D1	0.069	0.071	0.073
e	0.016 BSC		
L	0.008	0.010	0.012

Notes:

1. All dimensions are in millimeters. Converted inch dimensions are not necessarily exact.

Tape and Dimensions, DFN 2.5 mm x 1.2 mm

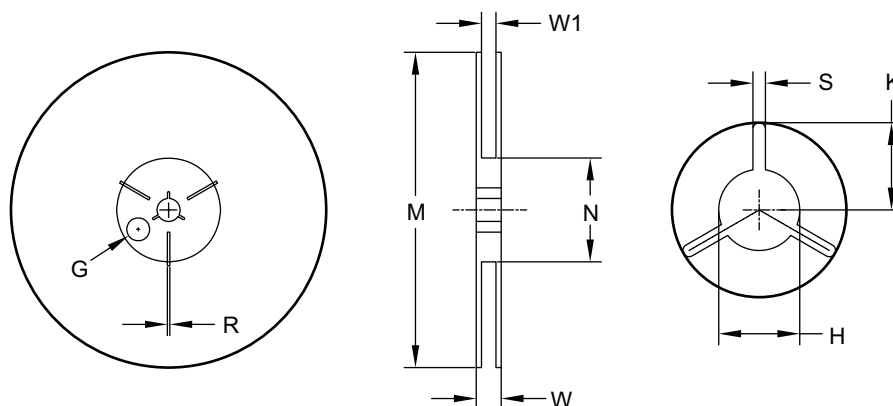
Carrier Tape



UNIT: mm

Package	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
DFN 2.5x1.2	1.45 ±0.05	2.80 ±0.05	0.70 ±0.05	ø1.55 ±0.05	ø0.80 ±0.05	8.00 ±0.03	1.75 ±0.1	3.50 ±0.05	4.00 ±0.10	4.0 ±0.10	2.0 ±0.05	0.30 ±0.05

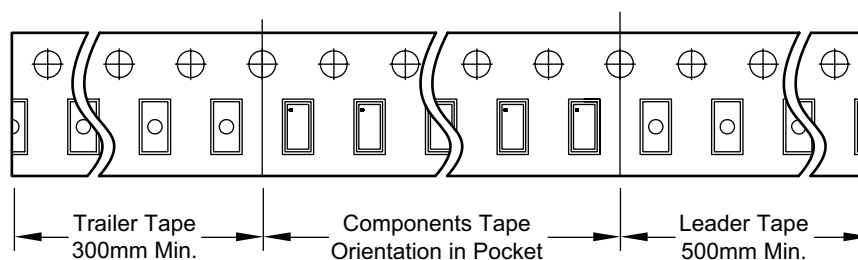
Reel



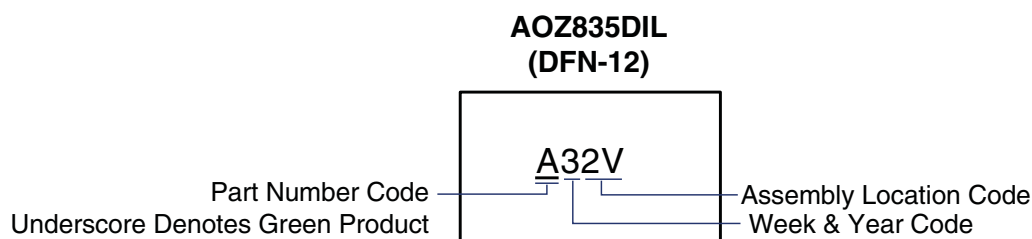
UNIT: mm

Tape Size	Reel Size	M	N	W	W1	H	S	K	E
8mm	ø178	ø178.0 ±1.0	ø60.0 ±0.5	11.80 ±0.5	9.0 ±0.5	ø13.0 +0.5 / -0.2	2.40 ±0.1	10.25 ±0.2	ø9.8

Leader / Trailer & Orientation



Package Marking



This data sheet contains preliminary data; supplementary data may be published at a later date.
Alpha & Omega Semiconductor reserves the right to make changes at any time without notice.

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.